

# isc Silicon NPN Power Transistor

### **DESCRIPTION**

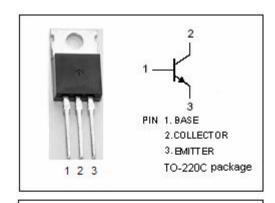
- Collector Power Dissipation: Pc= 30W
- · Collector-Emitter Breakdown Voltage-
  - : V<sub>(BR)CEO</sub>= 150V(Min.)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

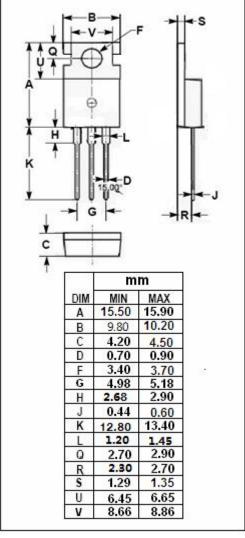
### **APPLICATIONS**

• Designed for TV vertical deflection output applications.

## ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>CBO</sub>	Collector-Base Voltage	200	V
Vceo	Collector-Emitter Voltage	150	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
lc	Collector Current-Continuous	2	Α
I <sub>CM</sub>	Collector Current-Peak	5	Α
Pc	Total Power Dissipation @ T <sub>a</sub> =25℃	1.8	W
	Total Power Dissipation @ T <sub>C</sub> =25°C	30	VV
TJ	Junction Temperature	150	$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature Range	-45~150	${\mathbb C}$







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2SD478

### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

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SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA; R <sub>BE</sub> = ∞	150			V		
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 5mA; I <sub>C</sub> = 0	6			V		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 0.5A; I <sub>B</sub> = 50mA			2.0	V		
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 50mA; V <sub>CE</sub> = 4V			1.0	V		
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 120V ; I <sub>E</sub> = 0			1	μА		
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 50mA; V <sub>CE</sub> = 4V	60		320			
h <sub>FE-2</sub>	DC Current Gain	Ic= 0.5A; V <sub>CE</sub> = 4V	60					
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 100V; f <sub>test</sub> = 1.0MHz		22		pF		

### ♦ h<sub>FE-1</sub> Classifications

В	С	D
60-120	100-200	160-320

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